74F543

Octal latched transceiver with dual enable; 3-state

Rev. 04 — 26 January 2010

Product data sheet

1. General description

The 74F543 octal latched transceiver contains two sets of D-type latches for temporary storage of data flowing in either direction. Separate latch enable ($\overline{\text{LEAB}}$, $\overline{\text{LEBA}}$) and output enable ($\overline{\text{OEAB}}$, $\overline{\text{OEBA}}$) inputs are provided for each register to permit independent control of data transfer in either direction. The A outputs are guaranteed to sink 24 mA while the B outputs are rated for 64 mA.

2. Features

- Combines 74F245 and 74F373 type functions in one device
- 8-bit octal transceiver with D-type latch
- Back-to-back registers for storage
- Separate controls for data flow in each direction
- A output capability: +20 mA to -3 mA
- B output capability: +64 mA to -15 mA
- 3-state outputs for bus-oriented applications

3. Ordering information

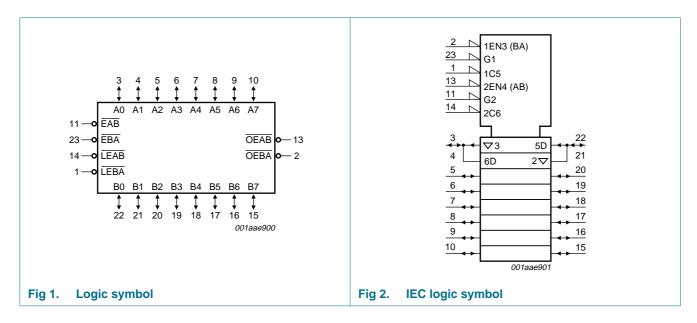
Table 1. Ordering information

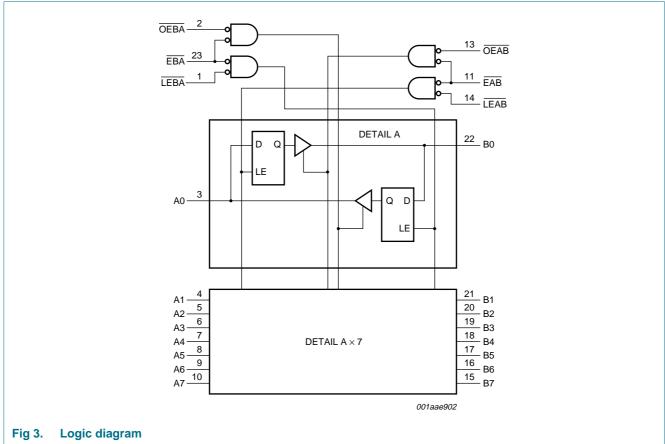
| Type number | Package | | | | | | | | |
|-------------|-------------------|--------|---|----------|--|--|--|--|--|
| | Temperature range | Name | Description | Version | | | | | |
| N74F543D | 0 °C to +70 °C | SO24 | plastic small outline package; 24 leads; body width 7.5 mm | SOT137-1 | | | | | |
| N74F543DB | 0 °C to +70 °C | SSOP24 | plastic shrink small outline package; 24 leads; body width 5.3 mm | SOT340-1 | | | | | |



Octal latched transceiver with dual enable; 3-state

4. Functional diagram

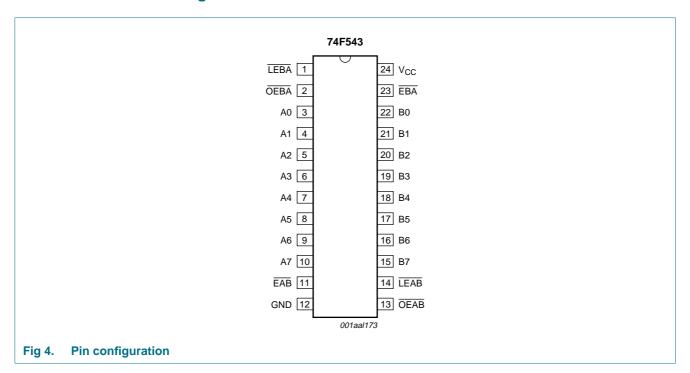




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5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2. Pin description

| Symbol | Pin | Description | Unit load HIGH/LOW | Load value[1] HIGH/LOW |
|----------|-----------------------------------|---|--------------------------------------|--|
| LEBA | 1 | B-to-A latch enable input (active LOW) | 1.0/1.0 | 20 μA/0.6 mA |
| OEBA | 2 | B-to-A output enable input (active LOW) | 1.0/1.0 | 20 μA/0.6 mA |
| A0 to A7 | 3, 4, 5, 6, 7, 8, 9, 10 | data input or output | inputs 3.5/1.0; outputs 150/40 | inputs 70 μA/0.6 mA; outputs 3.0 mA/24 mA |
| EAB | 11 | A-to-B enable input (active LOW) | 1.0/2.0 | 20 μA/1.2 mA |
| GND | 12 | ground (0 V) | | |
| OEAB | 13 | A-to-B output enable input (active LOW) | 1.0/1.0 | 20 μA/0.6 mA |
| LEAB | 14 | A-to-B latch enable input (active LOW) | 1.0/1.0 | 20 μA/0.6 mA |
| B0 to B7 | 22, 21, 20, 19, 18, 17, 16, 15 | data input or output | inputs 3.5/1.0; outputs 750/106.7 | inputs 70 μA/0.6 mA; outputs 15 mA/64 mA |
| EBA | 23 | B-to-A enable input (active LOW) | 1.0/2.0 | 20 μA/1.2 mA |
| V_{CC} | 24 | positive supply voltage | | |

^[1] One FAST Unit Load (UL) is defined as 20 μA in HIGH state, 0.6 μA in LOW state.

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Octal latched transceiver with dual enable; 3-state

Functional description

6.1 Function table

Table 3. Function selection[1]

| Input | | | Output | Status | |
|-------|------------|------------|----------|----------|------------------|
| OEXX | EXX | LEXX | An or Bn | Bn or An | |
| Н | X | X | X | Z | disabled |
| X | Н | Χ | Χ | Z | |
| L | \uparrow | L | h | Z | disabled + latch |
| | | | I | Z | |
| L | L | \uparrow | h | Н | latch + display |
| | | | I | L | |
| L | L | L | Н | Н | transparent |
| | | | L | L | |
| L | L | Н | Χ | NC | hold |

^[1] H = HIGH voltage level;

h = HIGH voltage level one set-up time prior to the LOW-to-HIGH clock transition of $\overline{\text{LEXX}}$ or $\overline{\text{EXX}}$ (XX = AB or BA);

I = LOW voltage level one set-up time prior to the LOW-to-HIGH clock transition of $\overline{\text{LEXX}}$ or $\overline{\text{EXX}}$ (XX = AB or BA);

 \uparrow = LOW-to-HIGH clock transition of \overline{LEXX} or \overline{EXX} (XX = AB or BA);

NC = no change;

X = don't care;

Z = high-impedance OFF-state.

6.2 Description

The 74F543 contains two sets of eight D-type latches, with separate control pins for each

Using data flow from A-to-B as an example, when the A-to-B enable (EAB) input, the A-to-B latch enable (\overline{LEAB}) input and the A-to-B output latch enable (\overline{OEAB}) are all LOW, the A-to-B path is transparent.

A subsequent LOW-to-HIGH transition of the LEAB signal puts the A data into the latches where it is stored and the B outputs no longer change with the A inputs. With EAB and OEAB both LOW, the 3-state B output buffers are active and display the data present at the outputs of the A latches.

Control of data flow from B-to-A is similar, but using the EBA, LEBA, and OEBA inputs.

Octal latched transceiver with dual enable; 3-state

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|------------------------|----------------------|-------------------|------|------|
| V_{CC} | supply voltage | | -0.5 | +7.0 | V |
| V_{I} | input voltage | | [<u>1</u>] -0.5 | +7.0 | V |
| V_{O} | output voltage | output in HIGH-state | [<u>1</u>] -0.5 | +5.5 | V |
| I_{IK} | input clamping current | V _I < 0 V | -30 | +5 | mA |
| Io | output current | output in LOW-state | | | |
| | | pins A0 to A7 | - | 48 | mA |
| | | pins B0 to B7 | - | 128 | mA |
| T _{amb} | ambient temperature | in free air | [2] 0 | 70 | °C |
| T _{stg} | storage temperature | | -65 | +150 | °C |

^[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

8. Recommended operating conditions

Table 5. Recommended operating conditions

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-----------------|---------------------------|---------------|-----|-----|-----|------|
| V_{CC} | supply voltage | | 4.5 | 5.0 | 5.5 | V |
| V_{IH} | HIGH-level input voltage | | 2.0 | - | - | V |
| V_{IL} | LOW-level input voltage | | - | - | 0.8 | V |
| I _{IK} | input clamping current | | - | - | -18 | mA |
| I _{OH} | HIGH-level output current | pins A0 to A7 | -3 | - | - | mA |
| | | pins B0 to B7 | -15 | - | - | mA |
| I _{OL} | LOW-level output current | pins A0 to A7 | - | - | 24 | mA |
| | | pins B0 to B7 | - | - | 64 | mA |

^[2] The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150 °C.

Octal latched transceiver with dual enable; 3-state

9. Static characteristics

Table 6. Static characteristics

| Symbol | Parameter | Conditions | | 25 °C | | 0 °C to | 70 °C | Unit |
|-----------------|--------------------------|---|-----|----------|-----|---------|-------|------|
| | | | Mi | n Typ[1] | Max | Min | Max | |
| / _{IK} | input clamping voltage | $V_{CC} = 4.5 \text{ V}; I_{IK} = -18 \text{ mA}$ | -1. | 2 –0.73 | - | -1.2 | - | ٧ |
| /он | HIGH-level output | V_{CC} = 4.5 V; V_{IL} = 0.8 V; V_{IH} = 2.0 V | | | | | | |
| | voltage | pins A0 to A7; $I_{OH} = -3 \text{ mA}$ | | | | | | |
| | | V _{CC} = ±10 % | - | - | - | 2.4 | - | V |
| | | V _{CC} = ±5 % | - | 3.4 | - | 2.7 | - | V |
| | | pins B0 to B7; $I_{OH} = -15 \text{ mA}$ | | | | | | |
| | | V _{CC} = ±10 % | - | - | - | 2.0 | - | V |
| | | V _{CC} = ±5 % | - | - | - | 2.0 | - | V |
| / _{OL} | LOW-level output | $V_{CC} = 4.5 \text{ V}; V_{IL} = 0.8 \text{ V}; V_{IH} = 2.0 \text{ V}$ | | | | | | |
| | voltage | pins A0 to A7; I _{OL} = 24 mA | | | | | | |
| | | V _{CC} = ±10 % | - | 0.35 | - | - | 0.5 | V |
| | | $V_{CC} = \pm 5 \%$ | - | 0.35 | - | - | 0.5 | ٧ |
| | | pins B0 to B7; I _{OL} = 64 mA | | | | | | |
| | | V _{CC} = ±10 % | - | - | - | - | 0.55 | ٧ |
| | | $V_{CC} = \pm 5 \%$ | - | 0.42 | - | - | 0.55 | ٧ |
| | input leakage current | V _{CC} = 5.5 V | | | | | | |
| | | pins \overline{OEAB} , \overline{OEBA} , \overline{EAB} ; V _I = 7.0 V | - | - | - | - | 100 | μΑ |
| | | other pins; $V_I = 5.5 \text{ V}$ | - | - | - | - | 1 | mΑ |
| IH | HIGH-level input current | $V_{CC} = 5.5 \text{ V}; V_{I} = 2.7 \text{ V}$ | - | - | - | - | 20 | μΑ |
| L | LOW-level input current | $V_{CC} = 5.5 \text{ V}; V_I = 0.5 \text{ V}$ | | | | | | |
| | | pins EAB, EBA | - | - | - | - | -1.2 | mΑ |
| | | other pins | - | - | - | - | -0.6 | mΑ |
| OZ | OFF-state output current | V _{CC} = 5.5 V | | | | | | |
| | | $V_0 = 2.7 \text{ V}; V_1 = 2.0 \text{ V}$ | - | - | - | - | 70 | μΑ |
| | | $V_O = 0.5 \text{ V}; V_I = 0.8 \text{ V}$ | - | - | - | - | -600 | μΑ |
| 0 | output current | V _{CC} = 5.5 V | [2] | | | | | |
| | | pins A0 to A7 | - | -60 | - | - | -150 | mΑ |
| | | pins B0 to B7 | - | -100 | - | - | -225 | mΑ |
| CC | supply current | V _{CC} = 5.5 V | | | | | | |
| | | outputs HIGH-state | - | 70 | - | - | 105 | mΑ |
| | | outputs LOW-state | - | 95 | - | - | 135 | mΑ |
| | | outputs OFF-state | - | 95 | - | - | 135 | mΑ |

^[1] All typical values are measured at V_{CC} = 5 V.

^[2] Not more than one output should be tested at a time, and the duration of the test should not exceed one second.

Octal latched transceiver with dual enable; 3-state

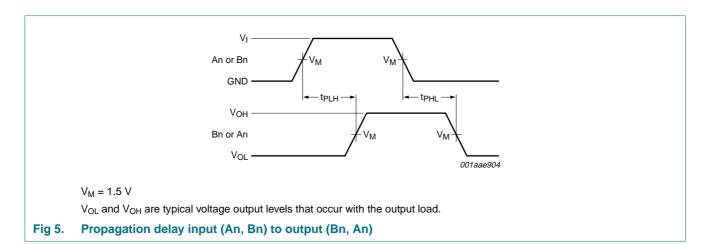
10. Dynamic characteristics

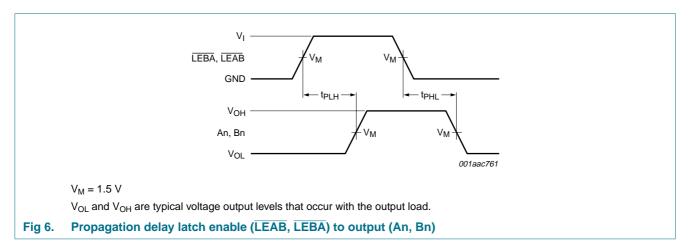
Table 7. Dynamic characteristics *GND = 0 V; for test circuit, see Figure 10.*

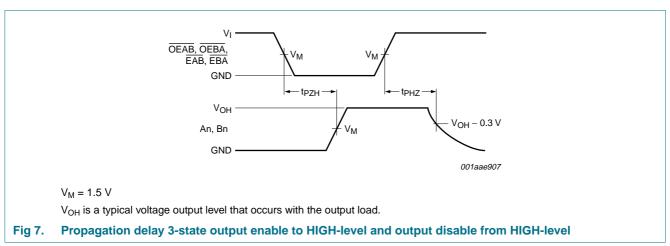
| Symbol | Parameter | Conditions | 25 °C | ; V _{CC} = | 5.0 V | | 70 °C; V ± 0.5 V | Unit |
|--------------------|-------------------|--------------------------------------|-------|---------------------|-------|-----|---------------------|------|
| | | | Min | Тур | Max | Min | Max | |
| t_{PLH} | LOW to HIGH | An to Bn; see Figure 5 | 3.5 | 5.5 | 8.5 | 3.0 | 9.0 | ns |
| | propagation delay | Bn to An; see Figure 5 | 2.5 | 4.0 | 7.0 | 2.5 | 7.5 | ns |
| | | LEBA to An; see Figure 6 | 5.0 | 7.0 | 10.0 | 4.5 | 11.0 | ns |
| | | LEAB to Bn; see Figure 6 | 6.0 | 8.5 | 11.5 | 5.5 | 12.5 | ns |
| t _{PHL} | HIGH to LOW | An to Bn; see Figure 5 | 3.0 | 5.0 | 8.0 | 2.5 | 8.5 | ns |
| | propagation delay | Bn to An; see Figure 5 | 2.5 | 4.5 | 7.5 | 2.5 | 8.0 | ns |
| | | LEBA to An; see Figure 6 | 4.0 | 6.0 | 9.0 | 4.0 | 9.5 | ns |
| | | LEAB to Bn; see Figure 6 | 4.5 | 6.5 | 9.5 | 4.0 | 10.0 | ns |
| t _{PZH} | OFF-state to HIGH | OEBA to An, OEAB to Bn; see Figure 7 | 2.0 | 4.0 | 7.5 | 1.5 | 8.0 | ns |
| | propagation delay | EBA to An, EAB to Bn; see Figure 7 | 4.5 | 7.0 | 10.5 | 4.0 | 11.5 | ns |
| t _{PZL} | OFF-state to LOW | OEBA to An, OEAB to Bn; see Figure 8 | 3.5 | 5.0 | 8.5 | 3.0 | 9.0 | ns |
| | propagation delay | EBA to An, EAB to Bn; see Figure 8 | 5.0 | 7.0 | 10.5 | 4.5 | 11.0 | ns |
| t _{PHZ} | HIGH to OFF-state | OEBA to An, OEAB to Bn; see Figure 7 | 1.0 | 3.0 | 6.5 | 1.0 | 7.5 | ns |
| | propagation delay | EBA to An, EAB to Bn; see Figure 7 | 2.5 | 5.0 | 8.5 | 2.0 | 9.5 | ns |
| t _{PLZ} | LOW to OFF-state | OEBA to An, OEAB to Bn; see Figure 8 | 1.5 | 4.0 | 7.5 | 1.0 | 8.5 | ns |
| | propagation delay | EBA to An, EAB to Bn; see Figure 8 | 4.5 | 7.0 | 11.0 | 3.0 | 12.0 | ns |
| t _{su(H)} | set-up time HIGH | An to LEAB, Bn to LEBA; see Figure 9 | 0.0 | - | - | 0.0 | - | ns |
| | | An to EAB, Bn to EBA; see Figure 9 | 1.0 | - | - | 1.5 | - | ns |
| t _{su(L)} | set-up time LOW | An to LEAB, Bn to LEBA; see Figure 9 | 2.5 | - | - | 3.0 | - | ns |
| | | An to EAB, Bn to EBA; see Figure 9 | 2.5 | - | - | 3.0 | - | ns |
| t _{h(H)} | hold time HIGH | An to LEAB, Bn to LEBA; see Figure 9 | 0.0 | - | - | 0.0 | - | ns |
| | | An to EAB, Bn to EBA; see Figure 9 | 0.0 | - | - | 0.0 | - | ns |
| t _{h(L)} | hold time LOW | An to LEAB, Bn to LEBA; see Figure 9 | 1.5 | - | - | 2.0 | - | ns |
| | | An to EAB, Bn to EBA; see Figure 9 | 1.5 | - | - | 2.0 | - | ns |
| t_{WL} | pulse width LOW | latch enable; see Figure 9 | 4.0 | - | - | 4.5 | - | ns |
| | | | | | | | | |

Octal latched transceiver with dual enable; 3-state

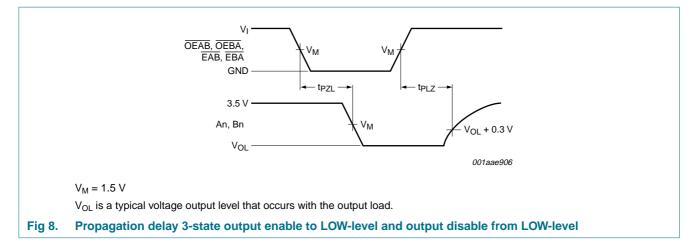
11. Waveforms







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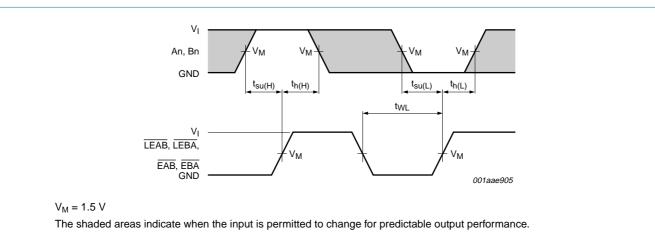
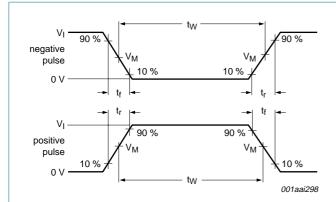
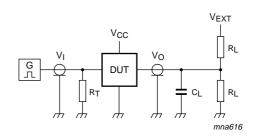


Fig 9. Data set-up and hold times and latch enable pulse width

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b. Test circuit

a. Input pulse definition

Test data is given in Table 8.

Definitions test circuit:

R_L = Load resistance.

C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator.

 V_{EXT} = External voltage for measuring switching times.

Fig 10. Load circuitry for switching times

Table 8. Test data

| Input | | | | Load | | V _{EXT} | | | |
|-------|----------------|----------------|---------------------------------|-------|----------------|-------------------------------------|-------------------------------------|-------------------------------------|--|
| VI | f _l | t _W | t _r , t _f | CL | R _L | t _{PHL} , t _{PLH} | t _{PZH} , t _{PHZ} | t _{PZL} , t _{PLZ} | |
| 3.0 V | 1 MHz | 500 ns | ≤ 2.5 ns | 50 pF | 500Ω | open | open | 7.0 V | |

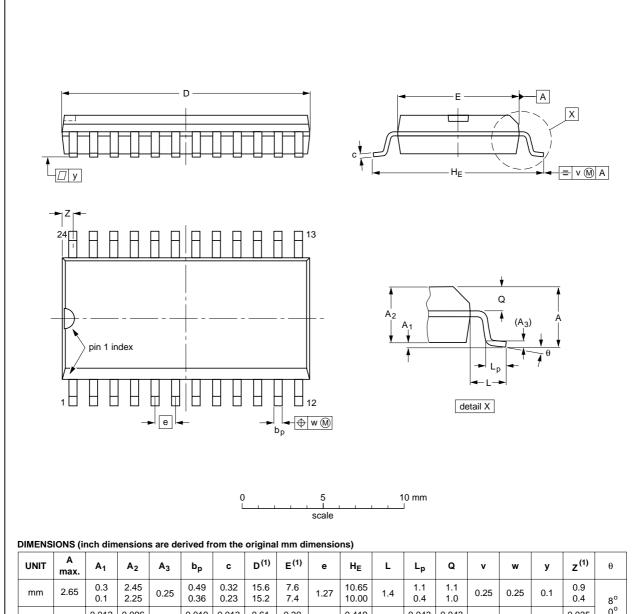
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12. Package outline

SO24: plastic small outline package; 24 leads; body width 7.5 mm

SOT137-1



| UNIT | A max. | A ₁ | A ₂ | A ₃ | bp | С | D ⁽¹⁾ | E ⁽¹⁾ | е | HE | L | Lp | Q | v | w | у | z ⁽¹⁾ | θ |
|--------|-----------|----------------|----------------|----------------|----------------|----------------|------------------|------------------|------|----------------|-------|----------------|----------------|------|------|-------|------------------|----|
| mm | 2.65 | 0.3 0.1 | 2.45 2.25 | 0.25 | 0.49 0.36 | 0.32 0.23 | 15.6 15.2 | 7.6 7.4 | 1.27 | 10.65 10.00 | 1.4 | 1.1 0.4 | 1.1 1.0 | 0.25 | 0.25 | 0.1 | 0.9 0.4 | 8° |
| inches | 0.1 | 0.012 0.004 | 0.096 0.089 | 0.01 | 0.019 0.014 | 0.013 0.009 | 0.61 0.60 | 0.30 0.29 | 0.05 | 0.419 0.394 | 0.055 | 0.043 0.016 | 0.043 0.039 | 0.01 | 0.01 | 0.004 | 0.035 0.016 | 0° |

Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

| OUTLINE | | REFER | ENCES | EUROPEAN | ISSUE DATE |
|----------|--------|--------|-------|------------|----------------------------------|
| VERSION | IEC | JEDEC | JEITA | PROJECTION | ISSUE DATE |
| SOT137-1 | 075E05 | MS-013 | | | -99-12-27 03-02-19 |

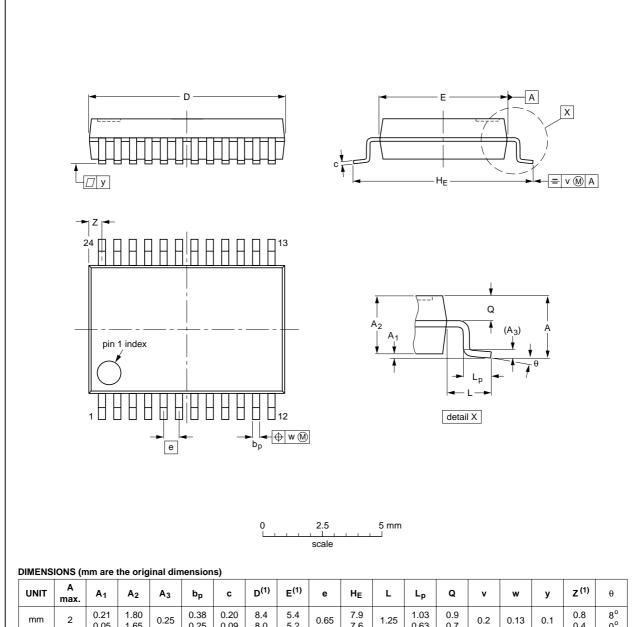
Fig 11. Package outline SOT137-1 (SO24)

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SSOP24: plastic shrink small outline package; 24 leads; body width 5.3 mm

SOT340-1



| UNIT | A max. | A ₁ | A ₂ | А3 | bp | C | D ⁽¹⁾ | E ⁽¹⁾ | е | HE | L | Lp | Q | v | w | у | z ⁽¹⁾ | θ |
|------|-----------|----------------|----------------|------|--------------|--------------|------------------|------------------|------|------------|------|--------------|------------|-----|------|-----|------------------|----------|
| mm | 2 | 0.21 0.05 | 1.80 1.65 | 0.25 | 0.38 0.25 | 0.20 0.09 | 8.4 8.0 | 5.4 5.2 | 0.65 | 7.9 7.6 | 1.25 | 1.03 0.63 | 0.9 0.7 | 0.2 | 0.13 | 0.1 | 0.8 0.4 | 8° 0° |

Note

1. Plastic or metal protrusions of 0.2 mm maximum per side are not included.

| OUTLINE | | REFER | EUROPEAN | ISSUE DATE | | |
|----------|-----|--------|----------|------------|------------|---------------------------------|
| VERSION | IEC | JEDEC | JEITA | | PROJECTION | ISSUE DATE |
| SOT340-1 | | MO-150 | | | | 99-12-27 03-02-19 |

Fig 12. Package outline SOT340-1 (SSOP24)

Octal latched transceiver with dual enable; 3-state

13. Abbreviations

Table 9. Abbreviations

| Acronym | Description |
|---------|---|
| BiCMOS | Bipolar Complementary Metal-Oxide Semiconductor |
| DUT | Device Under Test |
| ESD | ElectroStatic Discharge |
| HBM | Human Body Model |
| MM | Machine Model |

14. Revision history

Table 10. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes | |
|----------------|---|--|------------------------|-----------------------------|--|
| 74F543_4 | 20100126 | Product data sheet | - | 74F543_3 | |
| Modifications: | The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. | | | | |
| | Legal texts have been adapted to the new company name where appropriate. | | | | |
| | DIP 24 (SO 12 "Package | T222-1) package removed fr e outline" | rom Section 3 "Orderin | g information" and. Section | |
| 74F543_3 | 20040722 | Product specification | - | 74F543_544_2 | |
| 74F543_544_2 | 19941205 | Product specification | - | - | |

Octal latched transceiver with dual enable; 3-state

15. Legal information

15.1 Data sheet status

| Document status[1][2] | Product status[3] | Definition |
|--------------------------------|-------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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Octal latched transceiver with dual enable; 3-state

17. Contents

| 1 | General description | . 1 |
|------|----------------------------------|-----|
| 2 | Features | . 1 |
| 3 | Ordering information | . 1 |
| 4 | Functional diagram | . 2 |
| 5 | Pinning information | . 3 |
| 5.1 | Pinning | . 3 |
| 5.2 | Pin description | . 3 |
| 6 | Functional description | . 4 |
| 6.1 | Function table | . 4 |
| 6.2 | Description | . 4 |
| 7 | Limiting values | . 5 |
| 8 | Recommended operating conditions | . 5 |
| 9 | Static characteristics | . 6 |
| 10 | Dynamic characteristics | . 7 |
| 11 | Waveforms | . 8 |
| 12 | Package outline | 11 |
| 13 | Abbreviations | |
| 14 | Revision history | 13 |
| 15 | Legal information | 14 |
| 15.1 | Data sheet status | |
| 15.2 | Definitions | 14 |
| 15.3 | Disclaimers | 14 |
| 15.4 | Trademarks | 14 |
| 16 | Contact information | 14 |
| 17 | Contents | 15 |

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